



DMP2037U

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> TA = +25°C
-20V	28mΩ @ V <sub>GS</sub> = -4.5V	-6.1A
-200	43mΩ @ V <sub>GS</sub> = -2.5V	-4.9A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Load Switch

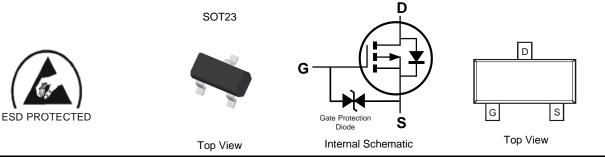
#### Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (93)
- Terminal Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2037U-7	SOT23	3,000 / Tape & Reel
DMP2037U-13	SOT23	10,000 / Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

N	/P4	MΥ	
Т			

MP4 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: H = 2020)

M = Month (ex: 9 = September)

Date Code Kev

Date Code Hoy												
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	N	0	Р	R	S
								<b>.</b>	0	0-1	New	Dee
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



#### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		Vdss	-20	V
Gate-Source Voltage		Vgss	±10	V
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$		lo	-6.1 -4.8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	-38	А	
Maximum Continuous Body Diode Forward Current (Note 6)		ls	-2.2	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	158	°C/W
Total Power Dissipation (Note 6)		PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>θJA</sub>	81	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	14.3	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						-
Drain-Source Breakdown Voltage	BVDSS	-20	_	—	V	$V_{GS} = 0V, I_D = -1mA$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	VGS(TH)	-0.5	_	-1.2	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
Static Drain-Source On-Resistance		_	20.3	28	mΩ	VGS = -4.5V, ID = -2A
Static Drain-Source On-Resistance	RDS(ON)	_	26.5	43	11122	$V_{GS} = -2.5V, I_D = -2A$
Diode Forward Voltage	Vsd	_	-0.66	-1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss		803	_		
Output Capacitance	Coss		114	-	pF	$V_{DS} = -10V$ , $V_{GS} = 0V$ f = 1MHz
Reverse Transfer Capacitance	Crss	_	51	_		
Gate Resistance	Rg	_	65.5	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = -8V)	Qg	_	14.5	_		
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	8.4	_	-0	
Gate-Source Charge	Qgs	_	1.5	—	nC	VDD = -10V, ID = -20A
Gate-Drain Charge	Q <sub>gd</sub>	_	1.9	_		
Turn-On Delay Time	tD(ON)	_	12	—		
Turn-On Rise Time	tR	_	6	—		$V_{GS} = -4.5V, V_{DD} = -10V,$
Turn-Off Delay Time	tD(OFF)	_	81	—	ns	$R_{G} = 1\Omega, I_{D} = -10A$
Turn-Off Fall Time	tF	_	46	—	]	

Notes:

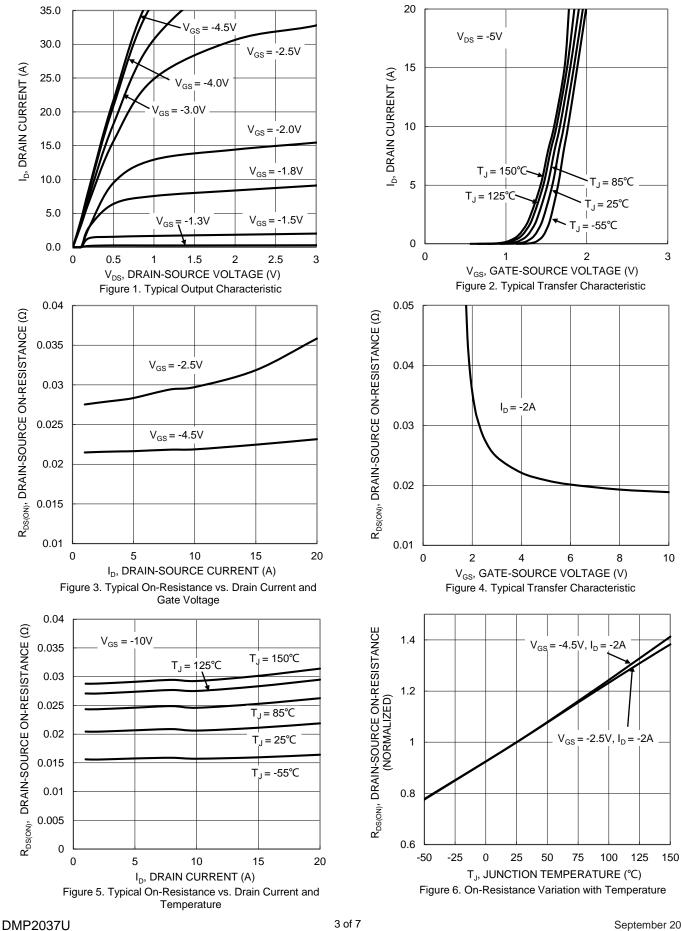
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



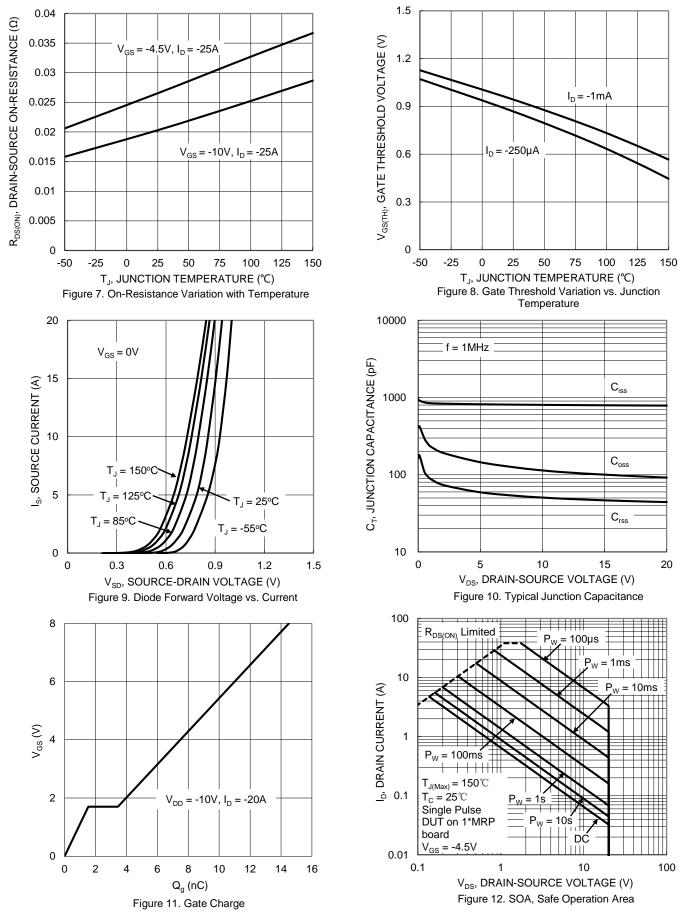
#### **DMP2037U**



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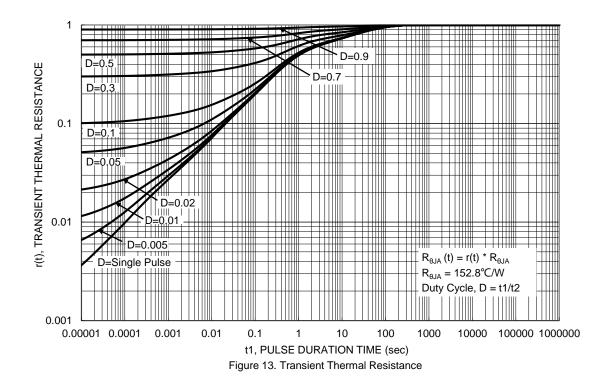


#### DMP2037U





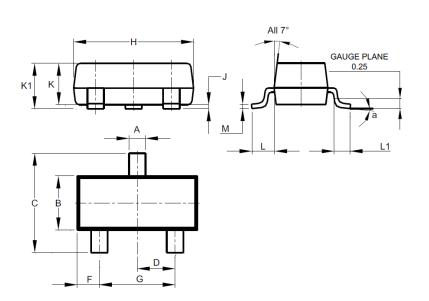






# **Package Outline Dimensions**

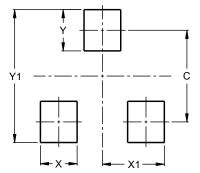
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
c	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
К	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
Μ	0.085	0.150	0.110				
а	0°	8°					
All	Dimens	ions in	mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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